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4 OpenSDA interface				A Prototype Production APR-14-2016 O. Romero
5   Power Supply/SWD				AX1 Development AUG-16-2016 O. Romero
6 I/O Headers				B 2nd Release SEP-02-2016 O. Romero
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		S32K144EVB-Q	2100	Soft William Cannon Drive West

Unless Otherwise Specified:
 All resistors are in ohms, 1% and 5 %

All capacitors are in uF,  $\,10\%$  , 20 % and  $\,5\%$ 

- All voltages are DC All polarized capacitors are aluminum electrolytic
- Interrupted lines coded with the same letter or letter combinations are electrically connected.
- 3. Device type number is for reference only. The number varies with the manufacturer.
- 4. Special signal usage:
  \_B Denotes Active-Low Signal
  <> or [] Denotes Vectored Signals
- 5. Interpret diagram in accordance with American National Standards Institute specifications, current revision, with the exception of logic block symbology.





















